

12500 TI Boulevard, MS 8640, Dallas, Texas 75243

PCN# 20140319001 Add Cu as Alternative Wire Base Metal for Selected Device(s) on QFN, QFP and SOT-23 packages Change Notification / Sample Request

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If you require samples or additional data to support your evaluation, please request within 30 days.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (PCN www admin team@list.ti.com).

Sincerely,

PCN Team SC Business Services Phone: +1(214) 480-6037 Fax: +1(214) 480-6659

PCN# 20140319001 Attachment: 1

Products Affected:

According to our records, there are the affected device(s) that you have purchased within the past twenty-four (24) months. Technical details of this Product Change follow on the next page(s).

PCN N	lumber	:	20140319001					PCN Date:		03/31/2014		
Title:		l Cu as A kages	lterna	ative Wire	Base	e Metal fo	or S	Selected Device(s) (on QFN, QI	FP and	SOT-23
Customer Contact:		PCN /	<u>Manager</u>		Phone	:	+1(214)480-603	37	Dept:	Quali	ty Services	
Propo	sed 1 st	Ship Da	ite:	07/01/20)14	Estima	ate	ed Sample Avai	lab	ility:		provided at ole request
Chang	је Туре	:										•
	Assem	bly Site				Design				Wafer Bu	ımp Si	te
		bly Proce				Data Sh	nee	t		Wafer Bu	ımp M	aterial
	Assem	bly Mate	rials			Part nui	mb	er change		Wafer Bu	ımp Pr	ocess
		nical Spe			<u> </u>	Test Sit				Wafer Fa		
	Packing	g/Shippiı	ng/La	beling		Test Pro	oce	SS		Wafer Fa		
									Ш	Wafer Fa	b Proc	ess
						PCN I	De	tails				
Descr	iption o	of Chan	ge:									
device piece piece piece piece	Texas Instruments is pleased to announce the qualification of Cu as an additional bond wire option for devices listed in "Product affected" section below. Devices will remain in current assembly facility and piece part changes as follows. Group 1 Device: No other piece part change											
Group	2 Dev	ice:		- Evons				To				
	Wire			From To 0.96 mil Au 0.80 mil Cu								
l	wire			0.96	11111 /	Au .		0.60 IIIII Cu				
Grour	3 Devi	ice										
Group	J DCV	icc.		From				То				
	Mold C	ompound	1	450207		1228		450413				
	Wire	ompoun		0.60, 0.80,	•			0.80, 1.0 mil C				
				7.00, 0.00,	, 1.0	IIIII Au		0.00, 1.0 11111 0	-u			
Reason for Change:												
1) To ele 2) Ma	 Continuity of supply. 1) To align with world technology trends and use wiring with enhanced mechanical and electrical properties 2) Maximize flexibility within our Assembly/Test production sites. 3) Cu is easier to obtain and stock 											
Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative):												
None.	None.											
Changes to product identification resulting from this PCN:												
None.	None.											
Produ	ict Affe	cted: Gi	oup	1 devices	3							
TPS6	5633AR	TER	TPS	S65633RT	ER	TP	S6	5633RTET				
Produ	ict Affe	cted: G	oup	2 devices	•							
DRV91670PHP DRV91670PHP-MC DRV91670PHPR												

Product Affected: Group 3 devices						
74AHC1G125DBVRE4	74LVC1GU04DBVRE4	SN74AUP1G125DBVR	SN74LVC1G80DBVRG4			
74AHC1G125DBVRG4	74LVC1GU04DBVRG4	SN74CBT1G125DBVR	SN74LVC1G86DBVR			
74AHC1G126DBVRE4	SN003166DBVR	SN74CBTLV1G125DBVR	SN74LVC1G86DBVRE4			
74AHC1G126DBVRG4	SN1003028DBVR	SN74LVC1G02DBVR	SN74LVC1G86DBVRG4			
74AHC1GU04DBVRE4	SN74AHC1G02DBVR	SN74LVC1G02DBVRE4	SN74LVC1GU04DBVR			
74AHC1GU04DBVRG4	SN74AHC1G02DBVRE4	SN74LVC1G02DBVRG4	TL343IDBVR			
74AHCT1G00DBVRE4	SN74AHC1G02DBVRG4	SN74LVC1G06DBVR	TL343IDBVRE4			
74AHCT1G00DBVRG4	SN74AHC1G04DBVR	SN74LVC1G06DBVRE4	TL343IDBVRG4			
74AHCT1G04DBVRE4	SN74AHC1G04DBVRE4	SN74LVC1G06DBVRG4	TL431ACDBVR			
74AHCT1G04DBVRG4	SN74AHC1G04DBVRG4	SN74LVC1G07DBVR	TL431ACDBVRE4			
74AHCT1G08DBVRE4	SN74AHC1G08DBVR	SN74LVC1G07DBVRE4	TL431ACDBVRG4			
74AHCT1G08DBVRG4	SN74AHC1G08DBVRE4	SN74LVC1G07DBVRG4	TL431CDBVR			
74AHCT1G125DBVRE4	SN74AHC1G08DBVRG4	SN74LVC1G126DBVR	TL431CDBVRE4			
74AHCT1G125DBVRG4	SN74AHC1G125DBVR	SN74LVC1G132DBVR	TL431CDBVRG4			
74AHCT1G126DBVRE4	SN74AHC1G126DBVR	SN74LVC1G14DBVR	TL431IDBVR			
74AHCT1G126DBVRG4	SN74AHC1G86DBVR	SN74LVC1G14DBVRE4	TL431IDBVRE4			
74AHCT1G32DBVRE4	SN74AHC1G86DBVRE4	SN74LVC1G14DBVRG4	TL431IDBVRG4			
74AHCT1G32DBVRG4	SN74AHC1G86DBVRG4	SN74LVC1G240DBVR	TLV431AIDBVR			
74AHCT1G86DBVRE4	SN74AHC1GU04DBVR	SN74LVC1G32DBVR	TLV431AIDBVRE4			
74AHCT1G86DBVRG4	SN74AHCT1G00DBVR	SN74LVC1G32DBVRE4	TLV431AIDBVRG4			
74AUP1G125DBVRE4	SN74AHCT1G04DBVR	SN74LVC1G32DBVRG4	TLV431CDBVR			
74AUP1G125DBVRG4	SN74AHCT1G08DBVR	SN74LVC1G34DBVR	TLV431CDBVRE4			
74CBT1G125DBVRE4	SN74AHCT1G125DBVR	SN74LVC1G34DBVRE4	TLV431CDBVRG4			
74CBT1G125DBVRG4	SN74AHCT1G126DBVR	SN74LVC1G34DBVRG4	TLV431IDBVR			
74CBTLV1G125DBVRE4	SN74AHCT1G32DBVR	SN74LVC1G66DBVR	TLV431IDBVRE4			
74CBTLV1G125DBVRG4	SN74AHCT1G86DBVR	SN74LVC1G66DBVRE4	TLV431IDBVRG4			
74LVC1G126DBVRE4	SN74AUP1G04DBVR	SN74LVC1G66DBVRG4	TS5A3166DBVR			
74LVC1G126DBVRG4	SN74AUP1G04DBVRE4	SN74LVC1G79DBVR	TS5A3166DBVRE4			
74LVC1G132DBVRE4	SN74AUP1G04DBVRG4	SN74LVC1G79DBVRE4	TS5A3166DBVRG4			
74LVC1G132DBVRG4	SN74AUP1G07DBVR	SN74LVC1G79DBVRG4	TS5A4594DBVR			
74LVC1G240DBVRE4	SN74AUP1G07DBVRE4	SN74LVC1G80DBVR	TS5A4594DBVRE4			
74LVC1G240DBVRG4	SN74AUP1G07DBVRG4	SN74LVC1G80DBVRE4	TS5A4594DBVRG4			

Qualification Data: Group 1 Devices

This qualification has been developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.

Qual Vehicle 1: TPA2017D2RTJ (MSL 2-260C)						
Package Construction Details						
Assembly Site:	TI-Clark	Mold Compound:	4208625			
# Pins-Designator, Family:	20-RTJ, QFN	Mount Compound:	4207768			
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wire:	0.96 Mil Dia., Cu			

Qualification: Plan Test Results							
Daliahilia Tark	Conditions		Sam		nple Size/Fail		
Reliability Test	Conditions			t# 1	Lot# 2	Lot# 3	
**High Temp Storage Bake	170C (420 Hrs)		86/0		87/0	87/0	
**Autoclave	121C (240 Hrs)		8	7/0	87/0	87/0	
**T/C -65C/150C	-65C/+150C (500 Cy	/c)	7	7/0	77/0	77/0	
X-ray	(top side only)		5	5/0	5/0	-	
Salt Atmosphere	24 Hours		2	2/0	22/0	22/0	
Surface Mount Solderability	8 Hours Steam Age-I	Pb Free Solder	2	2/0	22/0	22/0	
Manufacturability (Assembly)	(per mfg. Site specifi	ication)	P	ass	Pass	Pass	
Moisture Sensitivity	(level 2 @ 260C peal		1	2/0	12/0	12/0	
Notes **- Preconditioning s	equence: Level 2-2600	<u>.</u>					
Qua	Qual Vehicle 2: TPS2543QRTE (MSL 2-260C)						
Package Construction Details							
Assembly Site: 1	T-Clark	I-Clark Mold Compoun		4208	625		
# Pins-Designator, Family: 1	6-RTE, QFN Mount Compoun		nd:	4207	768		
Lead frame (Finish, Base): N	liPdAu, Cu Bond Wi			ire: 2.0 Mil Dia., Cu			
Qualification: Plan							
Daliahilia . Taak	Conditions		Sample Size/Fail				
Reliability Test			Lot# 1		Lot# 2	Lot# 3	
** Life Test	150C (408 Hrs)			7/0	77/0	77/0	
**High Temp Storage Bake	175C (500 Hrs)			8/0	80/0	79/0	
**Autoclave	121C (240 Hrs)			7/0	87/0	87/0	
**Biased HAST	130C/85%RH (96 Hrs)			7/0	77/0	77/0	
**Temperature Cycle	-65C/+150C (500 Cyc)			7/0	77/0	77/0	
Surface Mount Solderability	Pb Free/Solder-			5/0	15/0	-	
Manufacturability (Assembly)	(per mfg. Site specification)			ass	Pass	Pass	
Moisture Sensitivity	(level 2 @ 260C peak +5/-0C)			2/0	12/0	12/0	
Notes **- Preconditioning sequence: Level 2-260C.							

Qualification Data: Group 2 Devices

This qualification has been developed for the validation of this change. The qualification data

validates that the proposed change meets the applicable released technical specifications.						
Qual Vehicle 1: DRV91670PHPR (MSL 3-260C)						
Package Construction Details						
Assembly Site:	TAI	Mold Compound:	4205443			
# Pins-Designator, Family:	48-PHP, HTQFP	Mount Compound:	4208458			
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wire:	0.80 Mil Dia., Cu			

Qualification: Plan	▼ Test Results					
Poliphility Tost	Conditions	Sample Size/Fail				
Reliability Test	Conditions	Lot# 1	Lot# 2	Lot# 3		
Electrical Characterization	-	Pass	Pass	Pass		
**High Temp Storage Bake	170C (420 Hrs)	77/0	77/0	77/0		
**Autoclave	121C (96 Hrs)	77/0	77/0	77/0		
** Temperature Cycle	-65C/+150C (500 Cyc)	77/0	77/0	77/0		
ESD CDM	+/- 250V; +/- 1500V	3/0	-	-		
ESD HBM	+/- 1000V; +/- 2500V	3/0	-	-		
Manufacturability (Assembly)	(per mfg. Site specification)	Pass	Pass	Pass		
Moisture Sensitivity	(level 3 @ 260C peak +5/-0C)	12/0	-	-		
Notes **- Preconditioning se	equence: Level 3-260C.					

Qualification Data: Group 3 Devices								
This qualification has been developed for the validation of this change. The qualification data								
validates that the proposed change meets the applicable released technical specifications.								
Qual \	/ehicle 1: SN74AHC1		260	C)				
	Package Constr	uction Details						
Assembly Site:	HNT	Mold Compou	nd:	4504	13			
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compou	nd:	4001	54			
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	ire:	1.0 M	1il Dia., C	u		
Qualification: Plan								
Reliability Test	Conditions			San	nple Size/	Fail		
Reliability Test	Conditions	Conditions		t# 1	Lot# 2	Lot# 3		
**High Temp Storage Bake	170C (600 Hrs)	170C (600 Hrs)			85/0	84/0		
**Autoclave	121C (192 Hrs)			7/0	77/0	77/0		
** Temperature Cycle	-65C/+150C (500 Cy	-65C/+150C (500 Cyc)			77/0	77/0		
Moisture Sensitivity	(level 1 @ 260C peak +5/-0C)			22/0 22/0		22/0		
	sequence: Level 1-2600							
Qual Vehicle 2: SN74CBTLV1G125DBVR (MSL 1-260C)								
Package Construction Details								
Assembly Site:	HNT	Mold Compound: 4		450413				
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compound:		400154				
Lead frame (Finish, Base):				Vire: 0.8 Mil Dia., Cu				
Qualification: Plan Test Results								
Reliability Test	Conditions	Conditions			Sample Size/Fail			
**High Temp Storage Bake	170C (600 Hrs)	170C (600 Hrs)			90/0			
**Autoclave	121C (96 Hrs)			77/0				
**T/C -65C/150C	-65C/+150C (500 Cyc)			77/0				
Notes **- Preconditioning sequence: Level 1-260C.								

Qual Vehicle 3: SN74LVC1GU04DBVR (MSL 1-260C)							
	Package Constr	uction Details					
Assembly Site: HNT		Mold Compound:		450413			
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compou	nd:	4001	54		
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	re:	0.80	Mil Dia.,	Cu	
Qualification: Plan Test Results							
				San	nple Size/	'Fail	
Reliability Test	Conditions		Lot# 1		Lot# 2	Lot# 3	
**High Temp Storage Bake	170C (420 Hrs)		8	7/0	87/0	89/0	
**Autoclave	121C (192 Hrs)		7	7/0	77/0	77/0	
**Biased HAST	130C/85%RH (192 H	lrs)	8	0/0	80/0	80/0	
** Temperature Cycle	-65C/+150C (500 Cyc)			7/0	77/0	77/0	
Solderability	Pb Free/Solder			2/0	22/0	22/0	
Manufacturability (Assembly)	(per mfg. Site specifi	(per mfg. Site specification)			Pass	Pass	
Moisture Sensitivity	(level 1 @ 260C peal		2	2/0	22/0	22/0	
	sequence: Level 1-2600						
Qı	ual Vehicle 4: TS321		<u> </u>				
	Package Constr	uction Details					
Assembly Site:	INT Mold Compou		ınd: 450413				
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compound: 400154					
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	ire:	1.0 N	1il Dia., C	u	
Qualification: Plan	▼ Test Results						
S 1: 1:111	Sample Size/Fai				'Fail		
Reliability Test	Conditions	Conditions		t# 1	Lot# 2	Lot# 3	
**High Temp Storage Bake	170C (420 Hrs)	170C (420 Hrs)		9/0	80/0	80/0	
**Autoclave	121C (192 Hrs)	· · · · · · · · · · · · · · · · · · ·			77/0	77/0	
** Temperature Cycle	-65C/+150C (500 Cyc)			7/0	77/0	77/0	
Moisture Sensitivity	(level 1 @ 260C peak +5/-0C)			2/0	22/0	22/0	
Notes **- Preconditioning s	sequence: Level 1-2600	<u> </u>					

Qual Vehicle 5: TS5A3166DBVR (MSL 1-260C)						
Package Construction Details						
Assembly Site:	HNT	Mold Compound	d: 450413			
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compound	d: 400154			
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wire	e: 0.8 Mil Dia., Cu			
Qualification: Plan						
Reliability Test	Conditions	Conditions				
**Autoclave	121C (96 Hrs)	121C (96 Hrs)				
** Temperature Cycle	-65C/+150C (500 Cy	/c)	77/0			
Notes **- Preconditioning sequence: Level 1-260C.						

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com